

PNP SILICON PLANAR EPITAXIAL HIGH VOLTAGE	BF421
VIDEO TRANSISTORS	BF423
	TO-92 Plastic Package

## High Voltage Video Amplifier

 $E^{C}$ 

DESCRIPTION	SYMBOL	423	421	UNITS
Collector Emitter Voltage	V <sub>CEO</sub>	250	300	V
Collector Base Voltage	V <sub>CBO</sub>	250	300	V
Emitter Base Voltage	V <sub>EBO</sub>	5		V
Collector Current Continuous	I <sub>C</sub>	500	)	mA
Power Dissipation@ Ta=25 <sup>o</sup> C	P <sub>D</sub>	800	)	mW
Derate Above 25 <sup></sup> ℃		6.4	Ļ	mW/ºC
Power Dissipation@ Tc=25 <sup>o</sup> C	PD	2.7	5	W
Derate Above 25°C		22		mW/ºC
Operating And Storage Junction	T <sub>j</sub> , T <sub>stg</sub>	-55 to -	+150	°C
Temperature Range				
THERMAL RESISTANCE				
Junction to ambient	R <sub>th(j-a)</sub>	156	6	°C/W
Junction to case	R <sub>th(j-c)</sub>	45		°C/W

#### ELECTRICAL CHARACTERISTICS (Ta=25°C Unless Otherwise Specified)

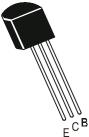
DESCRIPTION	SYMBOL	TEST CONDITION	423	421	UNITS
Collector Emitter Voltage*	$V_{CEO}$	I <sub>C</sub> =1.0mA,I <sub>B</sub> =0	>250	>300	V
Collector Base Voltage	$V_{CBO}$	I <sub>C</sub> =100μΑ.I <sub>E</sub> =0	>250	>300	V
EmitterBase Voltage	$V_{\text{EBO}}$	$I_{E}$ =100 $\mu$ A, $I_{C}$ =0	>5	>5	V
Collector-Cut off Current	I <sub>CBO</sub>	$V_{CB}=200V, I_{E}=0$	<10	<10	nA
Emitter-Cut off Current	I <sub>EBO</sub>	$V_{EB}$ =5.0V, $I_{C}$ =0	<100	<100	nA
DC Current Gain	h <sub>FE</sub>	$I_C=25mA, V_{CE}=20V$	>50	>50	
Collector Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_{C}=20mA, I_{B}=2mA$	<0.5	<0.5	V
Base Emitter Saturation Voltage	V <sub>BE(sat)</sub>	$I_{C}=20mA, I_{B}=2mA$	<2	<2	V

# PNP SILICON PLANAR EPITAXIAL HIGH VOLTAGE VIDEO TRANSISTORS

#### BF421 BF423

**TO-92** 

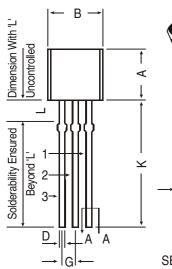
**Plastic Package** 



DESCRIPTION	SYMBOL	TEST CONDITION	423	421	UNITS
DYNAMIC CHARACTERISTICS					
Current Gain-Bandwidth Product	f <sub>T</sub>	I <sub>C</sub> =10mA, V <sub>CE</sub> =10V f=50MHz	>60	>60	MHz
Feedback Capacitance	$C_{re}$	V <sub>CB</sub> =30V, I <sub>E</sub> =0 f=1MHz	<2.8	<2.8	pF

#### **BF421 BF423**

### **TO-92 Plastic Package**



Т

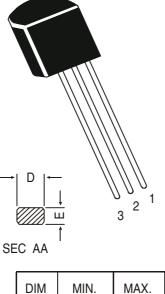
**PIN CONFIGURATION** 

2. COLLECTOR

3. EMITTER

2 1

1. BASE



4.32

4.45

3.18

0.41

0.35

1.14

1.14

12.70

All diminsions in mm.

1.982

5 DEG

A

В

С

D

Е

F

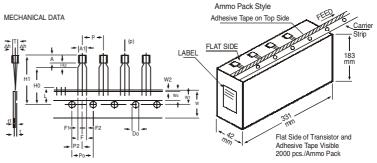
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L

**TO-92 Plastic Package TO-92 Transistors on Tape and Ammo Pack** 



#### All dimensions in mm unless specified otherwise

		SPECIFICATION				
ITEM	SYMBOL	MIN.	NOM.	MAX.	TOL .	REMARKS
BODY WIDTH BODY HEIGHT BODY THICKNESS PITCH OF COMPONENT	A1 A T P	4.0 4.8 3.9	12.7	4.8 5.2 4.2	±1	
FEED HOLE PITCH FEED HOLE CENTRE TO COMPONENT CENTRE	Po P2		12.7 6.35		±0.3 ±0.4	CUMULATIVE PITCH ERROR 1.0 mm/20 PITCH TO BE MEASURED AT
DISTANCE BETWEEN OUTER LEADS COMPONENT ALIGNMENT TAPE WIDTH HOLD-DOWN TAPE WIDTH HOLE POSITION	F △h Wo W1		5.08 0 18 6 9	1	+0.6 -0.2 ±0.5 ±0.2 +0.7 -0.5	BOTTOM OF CLINCH
HOLD-DOWN TAPE POSITION LEAD WIRE CLINCH HEIGHT COMPONENT HEIGHT LENGTH OF SNIPPED LEADS FEED HOLE DIAMETER TOTAL TAPE THICKNESS LEAD - TO - LEAD DISTANCEF1,	W2 Ho H1 Do t F2		0.5 16 4 2.54	23.25 11.0 1.2	$\pm 0.2 \\ \pm 0.5 \\ \pm 0.2 \\ \pm 0.2 \\ \pm 0.4 \\ \pm 0.1 \\ \pm 0.$	t1 0.3 - 0.6
CLINCH HEIGHT PULL - OUT FORCE	H2 (P)	6N		3	-0.1	

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5.33

5.20

4.19

0.55

0.50

1.40

1.53

2.082

AVERATING ALIGNMENT DEVIATION BETWEEN LEADS NOT TO BE GREATER THAN 0.2 mm.
MAXIMUM NON-CUMULATIVE VARIATION BETWEEN TAPE FEED HOLES SHALL NOT EXCEED 1 mm IN 20

HOLDDOWN TAPE NOT TO EXCEED BEYOND THE EDGE(S) OF CARRIER TAPE AND THERE SHALL BE NO 3. INDEDUCING OF ADHESIVE.
NO MORE THAN 3 CONSECUTIVE MISSING COMPONENTS ARE PERMITTED.
A TAPE TRAILER, HAVING AT LEAST THREE FEED HOLES ARE REQUIRED AFTER THE LAST COMPONENT.

6. SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

### **Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

Notes

#### BF421 BF423

TO-92 Plastic Package

#### Disclaimer

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Data Sheet